

SN54170, SN54LS170, SN74170, SN74LS170 4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

SDLS065 – MARCH 1974 – REVISED MARCH 1988

- Separate Read/Write Addressing Permits Simultaneous Reading and Writing
- Fast Access Times . . . Typically 20 ns
- Organized as 4 Words of 4 Bits
- Expandable to 1024 Words of n-Bits
- For Use as:
 - Scratch-Pad Memory
 - Buffer Storage between Processors
 - Bit Storage in Fast Multiplication Designs
- Open-Collector Outputs with Low Maximum Off-State Current:
 - '170 . . . 30 μ A
 - 'LS170 . . . 20 μ A
- SN54LS670 and SN74LS670 Are Similar But Have 3-State Outputs

description

The '170 and 'LS170 MSI 16-bit TTL register files incorporate the equivalent of 98 gates. The register file is organized as 4 words of 4 bits each and separate on-chip decoding is provided for addressing the four word locations to either write-in or retrieve data. This permits simultaneous writing into one location and reading from another word location.

Four data inputs are available which are used to supply the 4-bit word to be stored. Location of the word is determined by the write-address inputs A and B in conjunction with a write-enable signal. Data applied at the inputs should be in its true form. That is, if a high-level signal is desired from the output, a high level is applied at the data input for that particular bit location. The latch inputs are arranged so that new data will be accepted only if both internal address gate inputs are high. When this condition exists, data at the D input is transferred to the latch output. When the write-enable input, \overline{G}_W , is high, the data inputs are inhibited and their levels can cause no change in the information stored in the internal latches. When the read-enable input, \overline{G}_R , is high, the data outputs are inhibited and remain high.

The individual address lines permit direct acquisition of data stored in any four of the latches. Four individual decoding gates are used to complete the address for reading a word. When the read address is made in conjunction with the read-enable signal, the word appears at the four outputs.

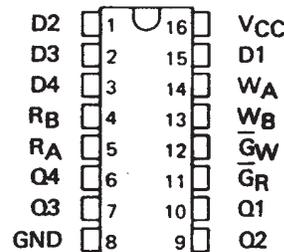
This arrangement—data-entry addressing separate from data-read addressing and individual sense line—eliminates recovery times, permits simultaneous reading and writing, and is limited in speed only by the write time (30 nanoseconds typical) and the read time (25 nanoseconds typical). The register file has a nondestructive readout in that data is not lost when addressed.

All '170 inputs and all inputs except the read enable and write enable of the 'LS170 are buffered to lower the drive requirements to one Series 54/74 or Series 54LS/74LS standard load, respectively. Input-clamping diodes minimize switching transients to simplify system design. High-speed, double-ended AND-OR-INVERT gates are employed for the read-address function and drive high-sink-current, open-collector outputs. Up to 256 of these outputs may be wire-AND connected for increasing the capacity up to 1024 words. Any number of these registers may be paralleled to provide n-bit word length.

The SN54170 and SN54LS170 are characterized for operation over the full military temperature range of -55°C to 125°C ; the SN74170 and SN74LS170 are characterized for operation from 0°C to 70°C .

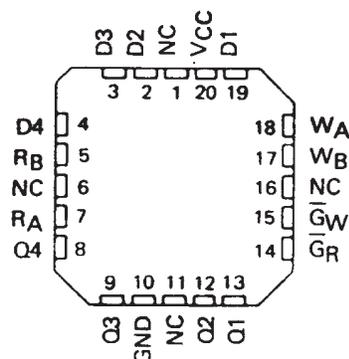
SN54170, SN54LS170 . . . J OR W PACKAGE
SN74170 . . . N PACKAGE
SN74LS170 . . . D OR N PACKAGE

(TOP VIEW)



SN54LS170 . . . FK PACKAGE

(TOP VIEW)



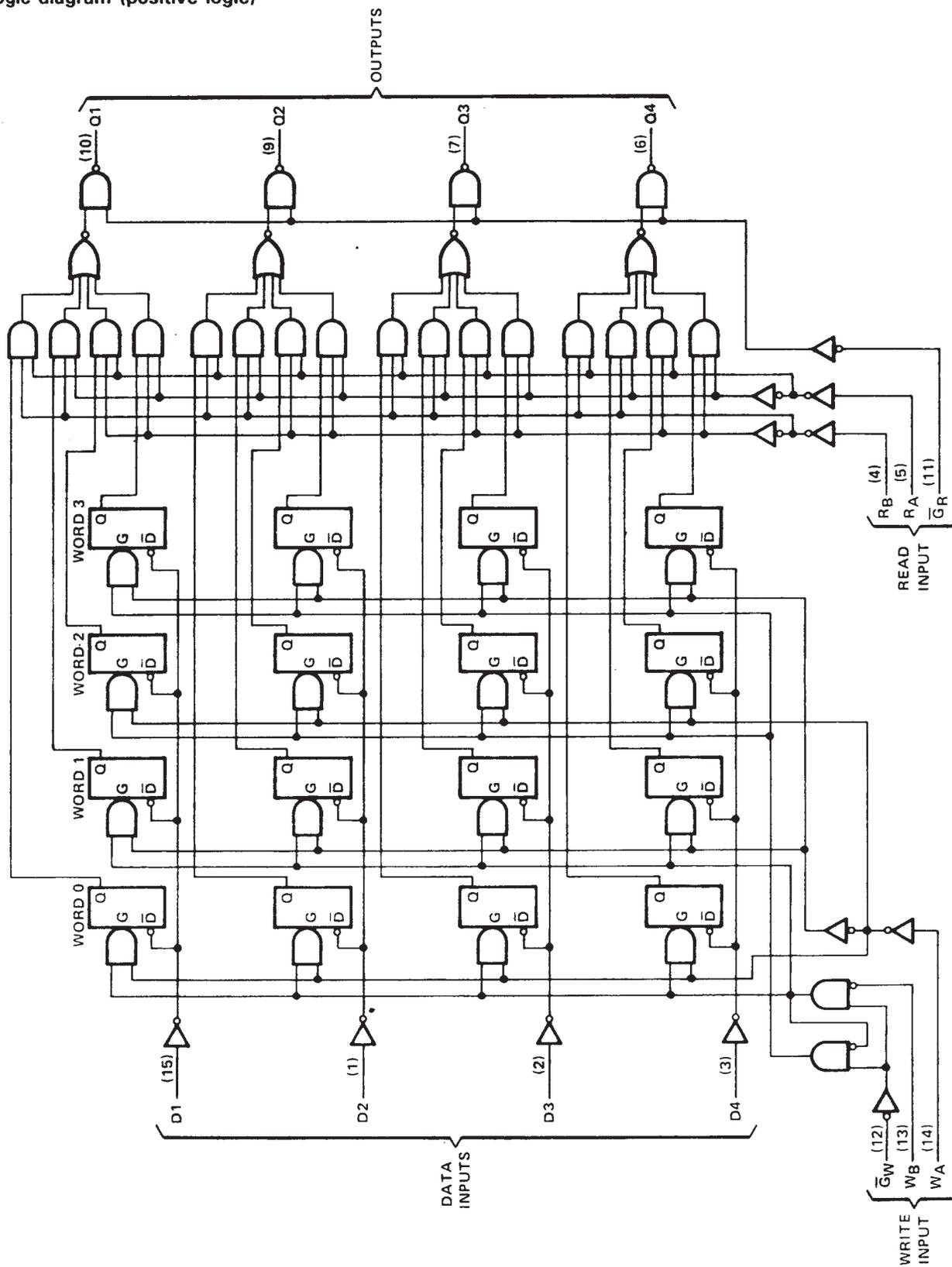
NC - No internal connection

SN54170, SN74170

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logic diagram (positive logic)



Pin numbers shown are for D, J, N, and W packages.



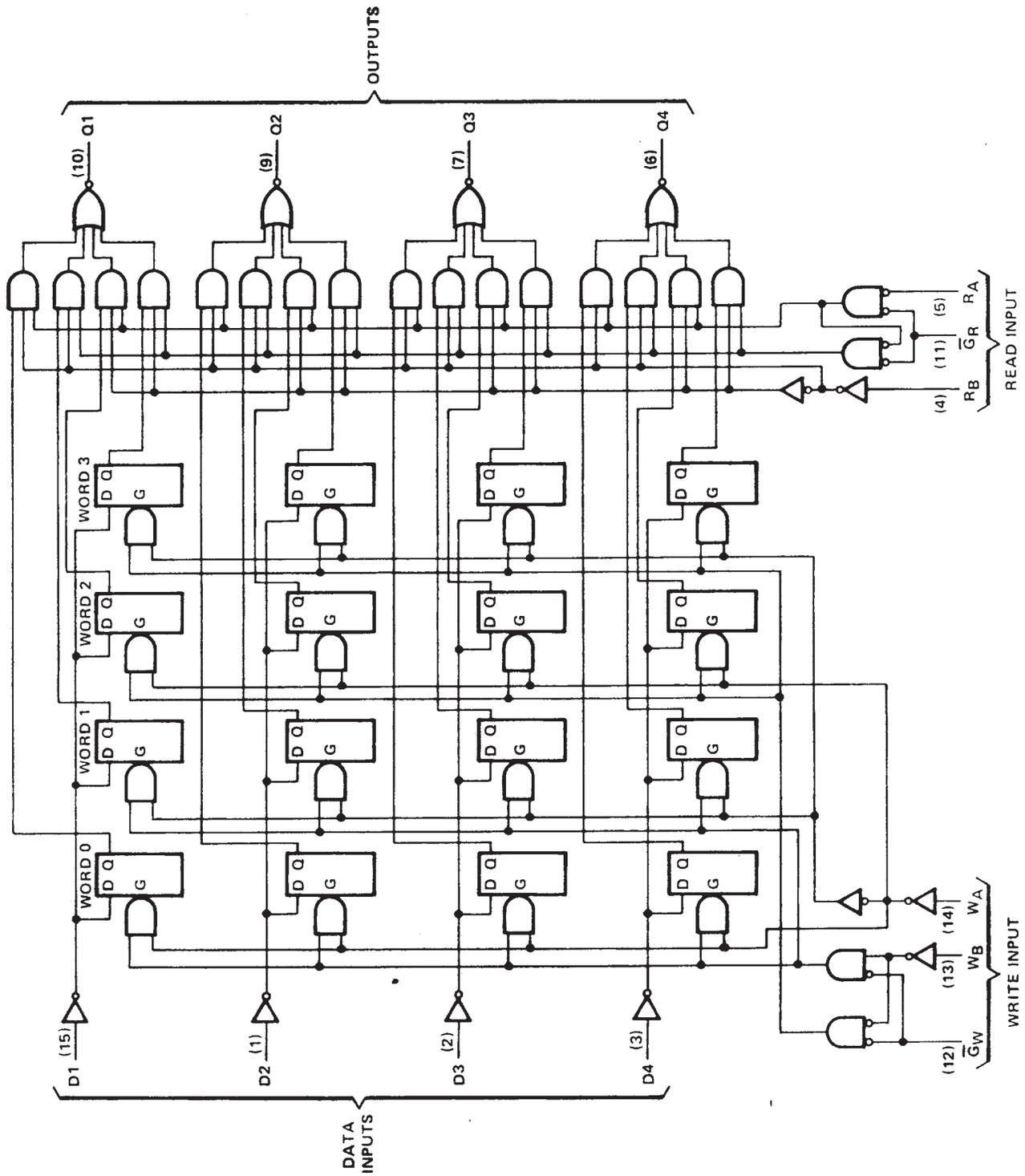
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SN54LS170, SN74LS170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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logic diagram (positive logic)



Pin numbers shown are for D, J, N, and W packages.

SN54170, SN74170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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recommended operating conditions

		SN54170			SN74170			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}		4.5	5	5.5	4.75	5	5.25	V
High-level output voltage, V_{OH}		5.5			5.5			V
Low-level output current, I_{OL}		16			16			mA
Width of write-enable or read-enable pulse, t_w		25			25			ns
Setup times, high- or low-level data (see Figure 2)	Data input with respect to write enable, $t_{su}(D)$	10			10			ns
	Write select with respect to write enable, $t_{su}(W)$	15			15			ns
Hold times, high- or low-level data (see Note 3 and Figure 2)	Data input with respect to write enable, $t_h(D)$	15			15			ns
	Write select with respect to write enable, $t_h(W)$	5			5			ns
Latch time for new data, t_{latch} (see Note 4)		25			25			ns
Operating free-air temperature range, T_A (see Note 2)		-55			125			0 70 °C

- NOTES: 2. An SN54170 in the W package operating at free-air temperatures above 105°C requires a heat sink that provides a thermal resistance from case to free-air, $R_{\theta CA}$, of not more than 38°C/W.
3. Write select setup time will protect the data written into the previous address. If protection of data in the previous address is not required, $t_{su}(W)$ can be ignored as any address selection sustained for the final 30 ns of the write-enable pulse and during $t_h(W)$ will result in data being written into that location. Depending on the duration of the input conditions, one or a number of previous addresses may have been written into.
4. Latch time is the time allowed for the internal output of the latch to assume the state of new data. See Figure 2. This is important only when attempting to read from a location immediately after that location has received new data.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	MIN	TYP‡	MAX	UNIT
V_{IH}	High-level input voltage		2			V
V_{IL}	Low-level input voltage				0.8	V
V_{IK}	Input clamp voltage	$V_{CC} = \text{MIN}, I_I = -12 \text{ mA}$			-1.5	V
I_{OH}	High-level output current	$V_{CC} = \text{MIN}, V_{OH} = 5.5 \text{ V}, V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}$			30	μA
V_{OL}	Low-level output voltage	$V_{CC} = \text{MIN}, V_{IH} = 2 \text{ V}, V_{IL} = 0.8 \text{ V}, I_{OL} = 16 \text{ mA}$	0.2	0.4		V
I_I	Input current at maximum input voltage	$V_{CC} = \text{MAX}, V_I = 5.5 \text{ V}$			1	mA
I_{IH}	High-level input current	$V_{CC} = \text{MAX}, V_I = 2.4 \text{ V}$			40	μA
I_{IL}	Low-level input current	$V_{CC} = \text{MAX}, V_I = 0.4 \text{ V}$			-1.6	mA
I_{CC}	Supply current	$V_{CC} = \text{MAX},$			127§	140 mA
		See Note 5	SN54170		127§	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡ All typical values are at $V_{CC} = 5 \text{ V}, T_A = 25^\circ \text{C}$.

§ Typical supply current shown is an average for 50% duty cycle.

NOTE 5: Maximum I_{CC} is guaranteed for the following worst-case conditions: 4.5 V is applied to all data inputs and both enable inputs, all address inputs are grounded, and all outputs are open.



SN54170, SN74170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

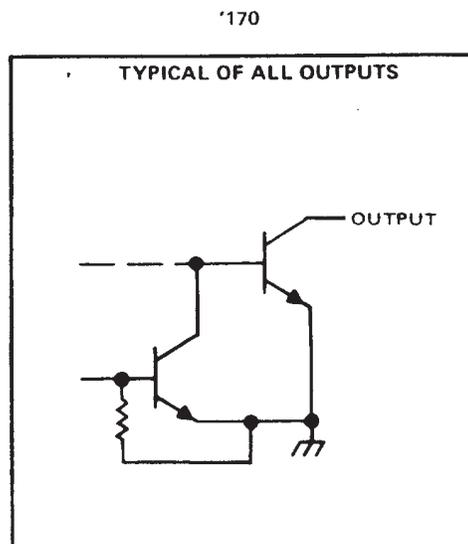
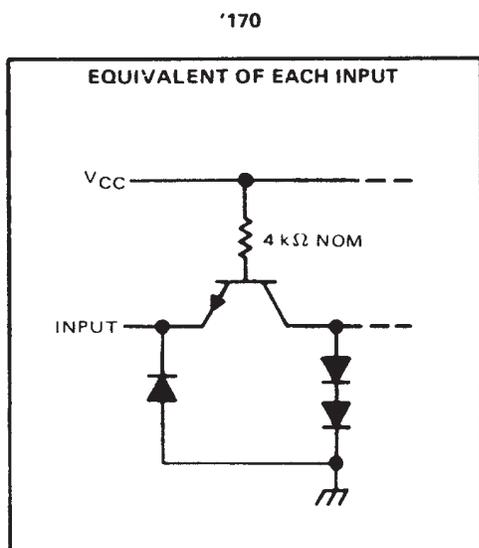
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switching characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Read enable	Any Q	$C_L = 15\text{ pF}$, $R_L = 400\ \Omega$, See Figures 1 and 2	10	15	ns	
t_{PHL}				20	30		
t_{PLH}	Read Select	Any Q		23	35	ns	
t_{PHL}				30	40		
t_{PLH}	Write enable	Any Q		25	40	ns	
t_{PHL}				34	45		
t_{PLH}	Data	Any Q	20	30	ns		
t_{PHL}			30	45			

† t_{PLH} = propagation delay time, low-to-high-level output
 t_{PHL} = propagation delay time, high-to-low-level output

schematics of inputs and outputs



SN54LS170, SN74LS170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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recommended operating conditions

		SN54LS170			SN74LS170			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}		4.5	5	5.5	4.75	5	5.25	V
High-level output voltage, V_{OH}		5.5			5.5			V
Low-level output current, I_{OL}		4			8			mA
Width of write-enable or read-enable pulse, t_w		25			25			ns
Setup times, high- or low-level data (see Figure 2)	Data input with respect to write enable, $t_{su(D)}$	10			10			ns
	Write select with respect to write enable, $t_{su(W)}$	15			15			ns
Hold times, high- or low-level data (see Note 3 and Figure 2)	Data input with respect to write enable, $t_h(D)$	15			15			ns
	Write select with respect to write enable, $t_h(W)$	5			5			ns
Latch time for new data, t_{latch} (see Note 4)		25			25			ns
Operating free-air temperature range, T_A		-55			125			0 70 °C

NOTES: 3. Write-select setup time will protect the data written into the previous address. If protection of data in the previous address is not required, $t_{su(W)}$ can be ignored as any address selection sustained for the final 30 ns of the write-enable pulse and during $t_h(W)$ will result in data being written into that location. Depending on the duration of the input conditions, one or a number of previous addresses may have been written into.

4. Latch time is the time allowed for the internal output of the latch to assume the state of new data. See Figure 2. This is important only when attempting to read from a location immediately after that location has received new data.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	SN54LS170			SN74LS170			UNIT
			MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V_{IH}	High-level input voltage		2			2			V
V_{IL}	Low-level input voltage		0.7			0.8			V
V_{IK}	Input clamp voltage	$V_{CC} = \text{MIN}, I_I = -18 \text{ mA}$	-1.5			-1.5			V
I_{OH}	High-level output current	$V_{CC} = \text{MIN}, V_{OH} = 5.5 \text{ V}, V_{IL} = V_{IL \text{ max}}, V_{IH} = 2 \text{ V}$	100			100			μA
V_{OL}	Low-level output voltage	$V_{CC} = \text{MIN}, V_{IH} = 2 \text{ V}, V_{IL} = V_{IL \text{ max}}$	$I_{OL} = 4 \text{ mA}$	0.25	0.4	0.25	0.4	V	
			$I_{OL} = 8 \text{ mA}$			0.35	0.5		
I_I	Input current at maximum input voltage	Any D, R, or \bar{W}	$V_{CC} = \text{MAX}, V_I = 7 \text{ V}$			0.1			mA
		\bar{G}_R or \bar{G}_W							
I_{IH}	High-level input current	Any D, R, or \bar{W}	$V_{CC} = \text{MAX}, V_I = 2.7 \text{ V}$			20			μA
		\bar{G}_R or \bar{G}_W							
I_{IL}	Low-level input current	Any D, R, or \bar{W}	$V_{CC} = \text{MAX}, V_I = 0.4 \text{ V}$			-0.4			mA
		\bar{G}_R or \bar{G}_W							
I_{CC}	Supply current	$V_{CC} = \text{MAX},$ See Note 5	25	40	25	40	mA		

†For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡All typical values are at $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$.

NOTE 5: I_{CC} is measured under the following worst-case conditions: 4.5 V is applied to all data inputs and both enable inputs, all address inputs are ground, and all outputs are open.



SN54LS170, SN74LS170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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recommended operating conditions

		SN54LS170			SN74LS170			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
Supply voltage, V_{CC}		4.5	5	5.5	4.75	5	5.25	V
High-level output voltage, V_{OH}		5.5			5.5			V
Low-level output current, I_{OL}		4			8			mA
Width of write-enable or read-enable pulse, t_w		25			25			ns
Setup times, high- or low-level data (see Figure 2)	Data input with respect to write enable, $t_{su}(D)$	10			10			ns
	Write select with respect to write enable, $t_{su}(W_L)$	15			15			ns
Hold times, high- or low-level data (see Note 3 and Figure 2)	Data input with respect to write enable, $t_h(D)$	15			15			ns
	Write select with respect to write enable, $t_h(W)$	5			5			ns
Latch time for new data, t_{latch} (see Note 4)		25			25			ns
Operating free-air temperature range, T_A		-55			125			0 70 °C

NOTES: 3. Write-select setup time will protect the data written into the previous address. If protection of data in the previous address is not required, $t_{su}(W)$ can be ignored as any address selection sustained for the final 30 ns of the write-enable pulse and during $t_h(W)$ will result in data being written into that location. Depending on the duration of the input conditions, one or a number of previous addresses may have been written into.

4. Latch time is the time allowed for the internal output of the latch to assume the state of new data. See Figure 2. This is important only when attempting to read from a location immediately after that location has received new data.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†	SN54LS170			SN74LS170			UNIT	
			MIN	TYP‡	MAX	MIN	TYP‡	MAX		
V_{IH}	High-level input voltage		2			2			V	
V_{IL}	Low-level input voltage		0.7			0.8			V	
V_{IK}	Input clamp voltage	$V_{CC} = \text{MIN}, I_I = -18 \text{ mA}$	-1.5			-1.5			V	
I_{OH}	High-level output current	$V_{CC} = \text{MIN}, V_{OH} = 5.5 \text{ V}, V_{IL} = V_{IL \text{ max}}, V_{IH} = 2 \text{ V}$	100			100			μA	
V_{OL}	Low-level output voltage	$V_{CC} = \text{MIN}, V_{IH} = 2 \text{ V}, V_{IL} = V_{IL \text{ max}}$	$I_{OL} = 4 \text{ mA}$	0.25	0.4	0.25	0.4	V		
			$I_{OL} = 8 \text{ mA}$			0.35	0.5			
I_I	Input current at maximum input voltage	$V_{CC} = \text{MAX}, V_I = 7 \text{ V}$	Any D, R, or \bar{W}	0.1			0.1			mA
			\bar{G}_R or \bar{G}_W	0.2			0.2			
I_{IH}	High-level input current	$V_{CC} = \text{MAX}, V_I = 2.7 \text{ V}$	Any D, R, or \bar{W}	20			20			μA
			\bar{G}_R or \bar{G}_W	40			40			
I_{IL}	Low-level input current	$V_{CC} = \text{MAX}, V_I = 0.4 \text{ V}$	Any D, R, or \bar{W}	-0.4			-0.4			mA
			\bar{G}_R or \bar{G}_W	-0.8			-0.8			
I_{CC}	Supply current	$V_{CC} = \text{MAX},$ See Note 5	25	40	25	40	mA			

†For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

‡All typical values are at $V_{CC} = 5 \text{ V}, T_A = 25^\circ\text{C}$.

NOTE 5: I_{CC} is measured under the following worst-case conditions: 4.5 V is applied to all data inputs and both enable inputs, all address inputs are ground, and all outputs are open.



SN54LS170, SN74LS170

4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

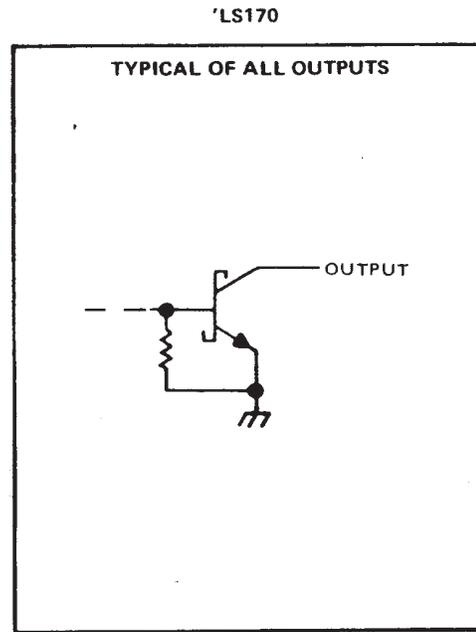
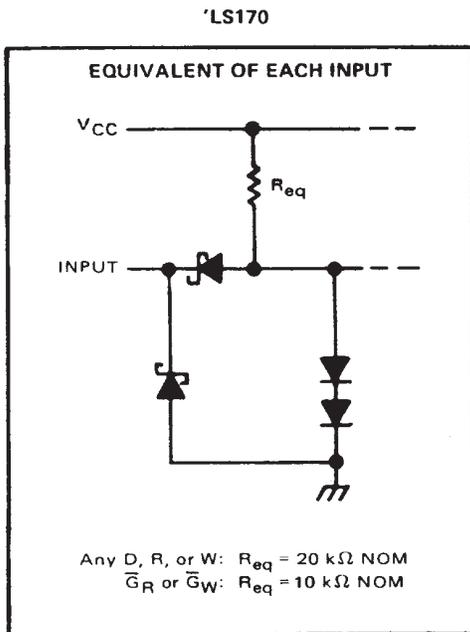
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switching characteristics, $V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$

PARAMETER†	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{PLH}	Read enable	Any Q	$C_L = 15\text{ pF}$, $R_L = 2\text{ k}\Omega$, See Figures 1 and 2	20	30	ns	
t_{PHL}				20	30		
t_{PLH}	Read select	Any Q		25	40	ns	
t_{PHL}				24	40		
t_{PLH}	Write enable	Any Q		30	45	ns	
t_{PHL}				26	40		
t_{PLH}	Data	Any Q	30	45	ns		
t_{PHL}			22	35			

† t_{PLH} = propagation delay time, low-to-high-level output
 t_{PHL} = propagation delay time, high-to-low-level output

schematics of inputs and outputs



SN54170, SN54LS170, SN74170, SN74LS170 4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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PARAMETER MEASUREMENT INFORMATION

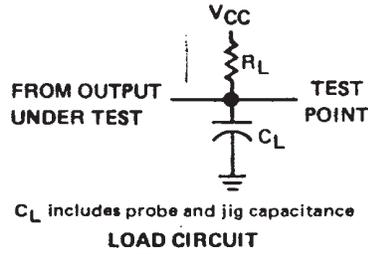
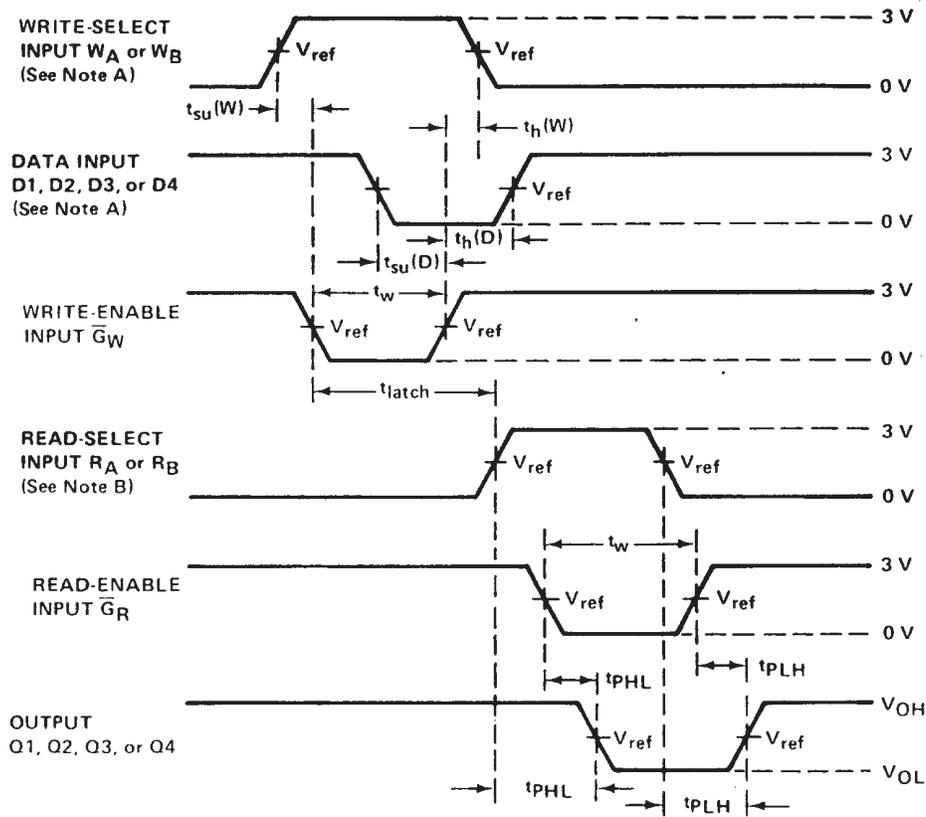


FIGURE 1



VOLTAGE WAVEFORMS

FIGURE 2

- NOTES:
- High-level input pulses at the select and data inputs are illustrated in Figure 2; however, times associated with low-level pulses are measured from the same reference points.
 - When measuring delay times from a read-select input, the read-enable input is low. When measuring delay times from the read-enable input, both read-select inputs have been established at steady states.
 - In Figure 3, each select address is tested. Prior to the start of each of the above tests, both write and read address inputs are stabilized with $W_A = R_A$ and $W_B = R_B$. During the test G_R is low.
 - Input waveforms are supplied by generators having the following characteristics: PRR ≤ 1 MHz, $Z_{out} \approx 50 \Omega$, duty cycle $< 50\%$, $t_r \leq 10$ ns and $t_f \leq 10$ ns for '170, and $t_r \leq 15$ ns and $t_f \leq 6$ ns for 'LS170.
 - For '170, $V_{ref} = 1.5$ V; for 'LS170, $V_{ref} = 1.3$ V.

SN54170, SN54LS170, SN74170, SN74LS170 4-BY-4 REGISTER FILES WITH OPEN-COLLECTOR OUTPUTS

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PARAMETER MEASUREMENT INFORMATION

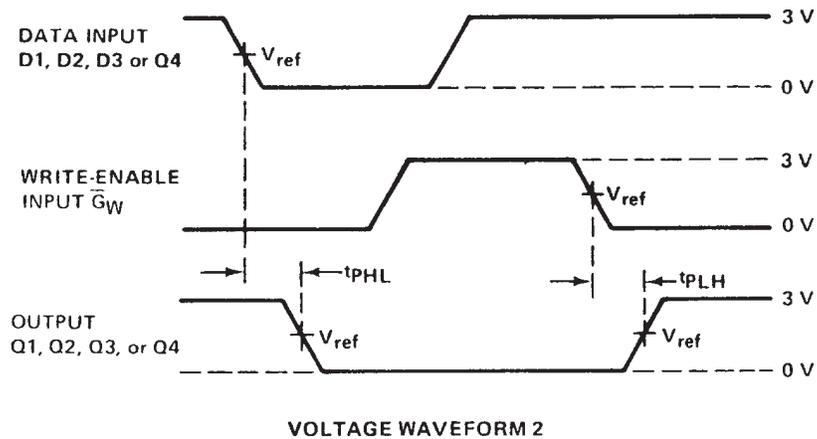
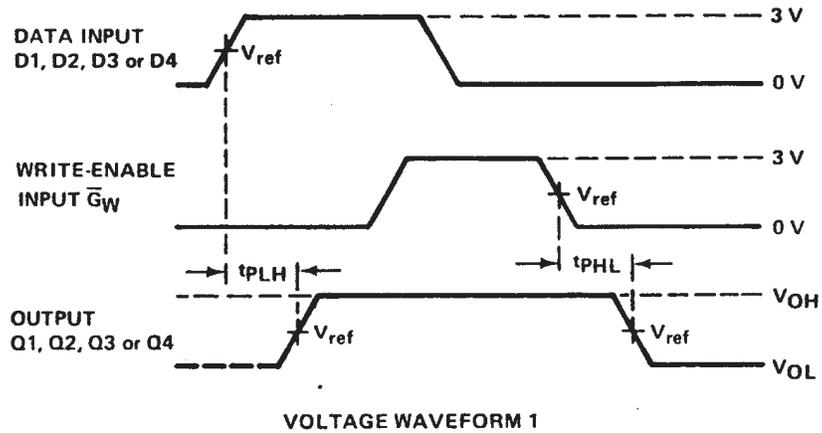


FIGURE 3

- NOTES: A. High-level input pulses at the select and data inputs are illustrated in Figure 2; however, times associated with low-level pulses are measured from the same reference points.
- B. When measuring delay times from a read-select input, the read-enable input is low. When measuring delay times from the read-enable input, both read-select inputs have been established at steady states.
- C. In Figure 3, each select address is tested. Prior to the start of each of the above tests, both write and read address inputs are stabilized with $W_A = R_A$ and $W_B = R_B$. During the test G_R is low.
- D. Input waveforms are supplied by generators having the following characteristics: $PRR \leq 1$ MHz, $Z_{out} \approx 50 \Omega$, duty cycle $\leq 50\%$, $t_r \leq 10$ ns and $t_f \leq 10$ ns for '170, and $t_r \leq 15$ ns and $t_f \leq 6$ ns for 'LS170.
- E. For '170, $V_{ref} = 1.5$ V; for 'LS170, $V_{ref} = 1.3$ V.